imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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SOT-26



Pin Definition:

1. Gate 1 6. Drain 1 2. Source 2 5. Source

2. Source 2 5. Source 1 3. Gate 2 4. Drain 2

Key Parameter Performance

Parameter		Value	Unit
V _{DS}		-20	V
$R_{DS(on)}\left(max ight)$	$V_{GS} = -4.5V$	140	
	$V_{GS} = -2.5V$	200	mΩ
	V _{GS} = -1.8V	300	
Qg		15.23	nC

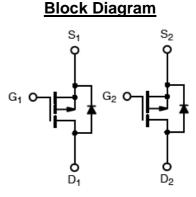
Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Ordering Information

Part No.	Package	Packing
TSM3911DCX6 RFG	SOT-26	3kpcs / 7" Reel

Note: "G" denotes for Halogen- and Antimony-free as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds



Dual P-Channel MOSFET

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	-20	V	
Gate-Source Voltage		V _{GS}	±8	V	
Continuous Drain Current		Ι _D	-2.2	А	
Pulsed Drain Current		I _{DM}	-8	А	
Continuous Source Current (Diode Conduction) (Note 1,2)		I _S	-0.72	А	
Movimum Dower Discinction	T _A = 25°C		1.15	w	
Maximum Power Dissipation	T _A =70°C	– P _D	0.73		
Operating Junction Temperature		TJ	+150	°C	
Operating Junction and Storage Temperature Range		T_J, T_STG	- 55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	RƏ _{JC}	30	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	RƏ _{JA}	80	°C/W



Electrical Specifications

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static (Note 3)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250 \mu A$	BV _{DSS}	-20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	V _{GS(TH)}	-0.45		-0.95	V
Gate Body Leakage	$V_{GS} = \pm 8V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -16V, V_{GS} = 0V$	I _{DSS}			-1.0	μA
On-State Drain Current	$V_{DS} = -5V, V_{GS} = -5V$	I _{D(ON)}	-5			Α
	$V_{GS} = -4.5V, I_{D} = -2.2A$			115	140	mΩ
Drain-Source On-State Resistance	$V_{GS} = -2.5V, I_D = -1.8A$	R _{DS(ON)}		163	200	
	$V_{GS} = -1.8V, I_{D} = -1A$			220	300	
Forward Transconductance	$V_{DS} = -5V, I_{D} = -2.2A$	g _{fs}		5		S
Diode Forward Voltage	$I_{S} = -1.05A, V_{GS} = 0V$	V _{SD}		- 0.8	-1.2	V
Dynamic ^(Note 4)						
Total Gate Charge	$V_{\rm DS} = -6V, I_{\rm D} = -2.8A,$	Qg		15.23		nC
Gate-Source Charge		Q _{gs}		5.49		
Gate-Drain Charge	- V _{GS} = -4.5V	Q _{gd}		2.74		
Input Capacitance		C _{iss}		882.51		
Output Capacitance	$V_{\rm DS} = -6V, V_{\rm GS} = 0V,$	C _{oss}		145.54		pF
Reverse Transfer Capacitance	f = 1.0MHz	C _{rss}		97.26		1
Switching (Note 4,5)						
Turn-On Delay Time		t _{d(on)}		17.28		
Turn-On Rise Time	$V_{DD} = -6V, R_L = 6\Omega,$ $I_D = -1A, V_{GEN} = -4.5V,$ $R_G = 6\Omega$	t _r		3.73]
Turn-Off Delay Time		t _{d(off)}		36.05		ns
Turn-Off Fall Time		t _f		6.19]

Notes:

1. Pulse width limited by the Maximum junction temperature

2. Surface Mounted on FR4 Board, $t \le 5$ sec.

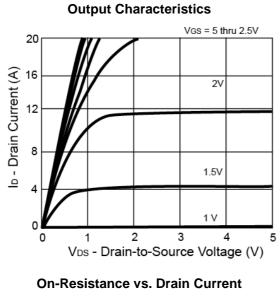
3. pulse test: PW \leq 300µS, duty cycle \leq 2%

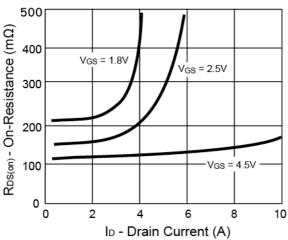
4. For DESIGN AID ONLY, not subject to production testing.

5. Switching time is essentially independent of operating temperature.

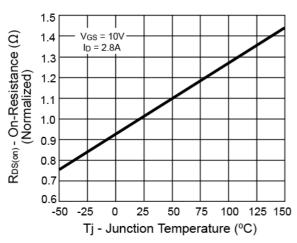


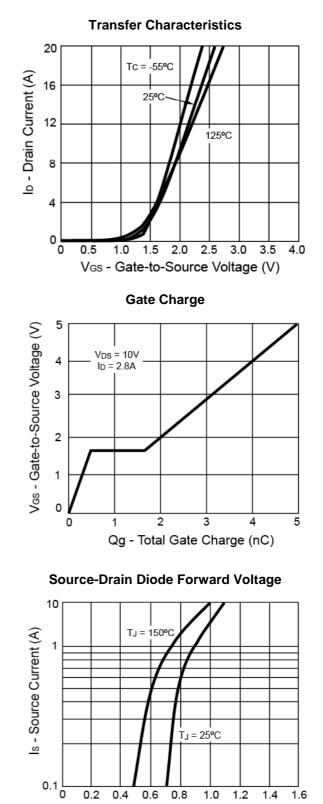
Electrical Characteristics Curves





On-Resistance vs. Junction Temperature





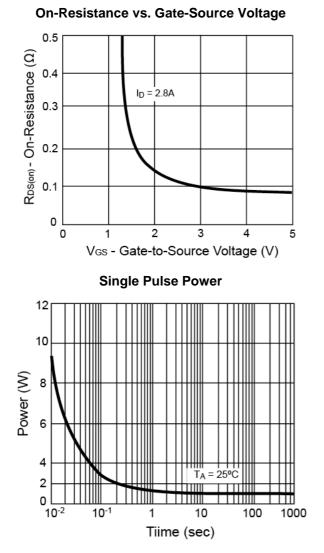
0.8 0.2 0.4 0.6 1.0 1.2 1.4 Vsp - Source-to-Drain Voltage (V)

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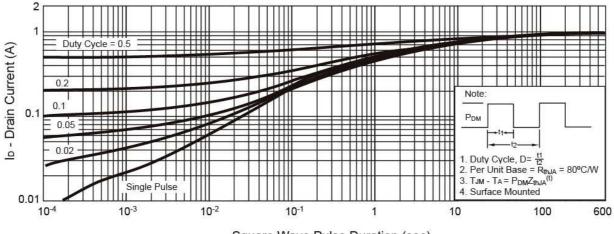


Electrical Characteristics Curves



Threshold Voltage 0.4 0.3 V_{GS(th)} - Variance (V) $I_{D} = 250 \mu A$ 0.2 0.1 0.0 -0.1 -0.2 -50 -25 0 25 50 75 100 125 150 Tj - Junction Temperature (°C)

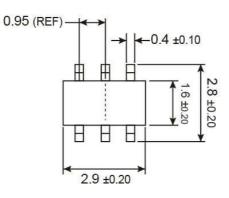
Normalized Thermal Transient Impedance, Junction-to-Ambient

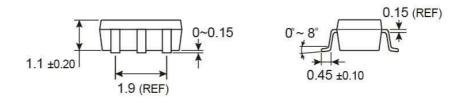


Square Wave Pulse Duration (sec)



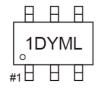
SOT-26 Mechanical Drawing





Unit: Millimeters

Marking Diagram



- **1D** = Device Code
- Y = Year Code
- **M** = Month Code for Halogen Free Product

	O =Jan	P =Feb	Q	=Mar	R =Apr
	S =May	T =Jun	U	=Jul	V =Aug
	W =Sep	X =Oct	Υ	=Nov	Z =Dec
L	= Lot Code				



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